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|  | <h2>SI1302DL-T1-E3</h2> |
| | <p>Hersteller-Teilenummer: SI1302DL-T1-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 600MA SOT323-3</p> <p>Datenblätter:  SI1302DL-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3810 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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|--|---|
| Teilenummer | SI1302DL-T1-E3 |
| Hersteller | Electro-Films (EFI) / Vishay |
| Beschreibung | MOSFET N-CH 30V 600MA SOT323-3 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | 3810 pcs Stock |
| Hersteller Standard Vorlaufzeit | 33 Weeks |
| detaillierte Beschreibung | N-Channel 30V 600mA (Ta) 280mW (Ta) Surface |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | SC-70, SOT-323 |
| Supplier Device-Gehäuse | SC-70-3 |
| Verlustleistung (max) | 280mW (Ta) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 600mA (Ta) |
| Rds On (Max) @ Id, Vgs | 480 mOhm @ 600mA, 10V |
| VGS (th) (Max) @ Id | 3V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 1.4nC @ 10V |
| Antriebsspannung (Max Rds On, Min Rds On) | 4.5V, 10V |
| Vgs (Max) | ±20V |
| Verpackung | Cut Tape (CT) |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |
| Andere Namen | SI1302DL-T1-E3CT |

SI1302DL-T1-E3 ist neu im Original, Suche SI1302DL-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1302DL-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1302DL-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

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|  SI1302DL-T1 VISHAY SI1302DL-T1 VISHAY |  SI1301DL-T1-GE3 V SI1301DL-T1-GE3 V |  SI1303DL VISHAY SI1303DL VISHAY |  SI1303DL-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 670MA SOT323-3 |
|  SI1302DL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 600MA SC-70-3 |  SI1301DL-T1/LGW VISHAY SI1301DL-T1/LGW VISHAY |  SI1302DL VISHAY SI1302DL VISHAY |  SI1303DL-T1 VISHAY SI1303DL-T1 VISHAY |

heiße Teile

Mehr

| | | | | |
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| SI1072X-T1-GE3 | SI1073X-T1-GE3 | SI1073X-T1-GE3 | D SI1120-A-GMR | SI1132-A10-GMR |
| SI1133-AA00-GMR | SI113DP-T1-GE3 | D SI1141-A10-GMR | SI1142-A11-GMR | SI1143-A11-GMR |
| SI1143-M01-GMR | SI1144-AAGX-GMR | SI1300BDL-T1-E3 | SI1300BDL-T1-E3 | SI1300BDL-T1-GE3 |
| D SI1300BDL-T1-GE3 | SI1300DL | SI1300DL-T1 | SI1300DL-T1-GE3 | SI1301DL |
| SI1301DL-T1 | SI1301DL-T1-E3 | SI1301DL-T1-GE3 | SI1301DL-T1/LGW | SI1302DL |
| SI1302DL-T1-E3 | SI1302DL-T1-GE3 | D SI1302DL-T1-GE3 | SI1303DL | SI1303DL-T1 |
| SI1303DL-T1-E3 | D SI1303DL-T1-E3 | SI1303DL-T1-GE3 | SI1303DL-T1-GE3 | SI1303DL-TL-E3 |
| SI1303EDL-T1-GE3 | SI1304BDL-T1-GE3 | SI1304BDL-T1-GE3 | SI1304DL | SI1304DL-L |
| SI1304DL-T1 | SI1304DL-T1-E3 | SI1304DL-T1-GE3 | D SI1305DL | SI1305DL-T1 |
| SI1305DL-T1-E3 | SI1305DL-T1-E3 | SI1305DL-T1-GE3 | SI1305DL-T1-GE3 | SI1305DL-TI-E3 |

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